

	Type	Hits	Search Text	DBs
1	BRS	456	((hafnium adj oxide) or hafnium) with (gate adj dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
2	BRS	2	S1 and (hydrogen with anneal) and (oxygen with anneal)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
3	BRS	303	S1 and anneal\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
4	BRS	227	S3 and (hafnium adj oxide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB

	Type	Hits	Search Text	DBs
5	BRS	456	((hafnium adj oxide) or hafnium) with (gate adj dielectric)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
6	BRS	254	((hafnium adj oxide) or hafnium) and (gate adj dielectric) and anneal\$3 and hydrogen and oxygen	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
7	BRS	20	((hafnium adj oxide) or hafnium) and (gate adj dielectric) and anneal\$3 and hydrogen and oxygen and diamond	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
8	BRS	1	((hafnium adj oxide) or hafnium) and (gate adj dielectric) and (diamond adj substrate)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB

	Type	Hits	Search Text	DBs
9	BRS	5881	438/240,261,287,585,591,765,770-772,765,775-778,785.ccls.	US-PGPUB; USPAT
10	BRS	91	S9 and ((hafnium adj oxide) or hafnium) and (gate adj dielectric) and anneal\$3 and hydrogen and oxygen	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM TDB
11	BRS	91	S9 and ((hafnium adj oxide) or hafnium) and (gate adj dielectric) and anneal\$3 and hydrogen and oxygen	US-PGPUB; USPAT